

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

**APPLICANT:** Tuller et al. **GROUP:** 2815  
**SERIAL NO:** 10/663,531 **EXAMINER:** M. Landau  
**FILED:** September 16, 2003  
**FOR:** **METHOD FOR P-TYPE DOPING OF WIDE BAND GAP  
OXIDE SEMICONDUCTORS**

**Commissioner of Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450**

**Sir:**

**AMENDMENT**

In response to the Office Action mailed July 9, 2008, please amend the above-identified application as follows: